Comprehensive Analysis of Shielding Effectiveness of Enclosures with Apertures: Parametrical Approach

Ibrahim B. Başyığıt* and Mehmet F. Çağlar

Abstract—The main section of this paper comprehensively analyzes electrical shielding effectiveness (ESE) of enclosures with rectangular apertures for producing valuable information used in electromagnetic interference and compatibility guiding enclosure designers of electronic devices. Firstly, results of conventional analytical equivalent circuit model, measurement and simulation with computer simulating technology (CST™) of ESE for an enclosure with a single aperture size are compared to improve closeness in different models at 0–1 GHz. After getting a suitable simulation model, all possible parameters with detailed cases are examined to approach beneficial conclusions. Especially, size of enclosure, aperture size, aperture shape, configuration and number of apertures, probe position parameters that affect ESE are investigated. Also, some double parameters are analyzed together to achieve detailed review as two enclosure dimensions, two aperture dimensions and probe position with enclosure depth. Therefore, three-dimensional graphical investigations are performed. Obtained results of these parametric approaches are explained with acceptable reasons. Finally, detailed and itemized comments are given about simulated results of ESE parameters, which are collected from previous sections.

1. INTRODUCTION

Electromagnetic shielding is usually used to decrease the emissions or to the progress of equipment immunity. By increasing used shielding enclosures for electronics systems, apertures and slots of these enclosures come into prominence for heat allocation, ventilation, I/O cable, etc. These slots and apertures induce the coupling route of electromagnetic interference (EMI) from the inside to outside [1]. So, metallic shielding enclosures are generally used to reduce radiation from external electromagnetic fields and exudation effects from interior devices. The general definition of the shielding effectiveness (SE) according to the IEEE Standard 299 (IEEE Standard Method for Measuring the Effectiveness of Electromagnetic Shielding Enclosures) [2] is generally used to determine the efficiency of a shield. Electrical shielding effectiveness (ESE) can be identified in Eq. (1). $E_a$ and $E_b$ are the electric field strengths with absence and presence of enclosure, respectively

$$ESE = 10\log_{10} \frac{E_a}{E_b} \text{[dB]} \quad (1)$$

Robinson et al. [3] claimed an analytical formulation based on a transmission line model, where the rectangular enclosure and aperture are modeled by a short-circuit rectangular waveguide and a coplanar strip transmission line, respectively. There are also many studies on analytical method on ESE of enclosures with apertures: New formulas based on electromagnetic [4–7], circuit models [8–10], transmission line theory [11] and surface equivalent principles [12] are some of the analytical methods
used to calculate ESE. These analytical methods are common and accurate but can be applied only to very simple geometries with approximations.

There are numeric methods to calculate ESE of enclosures with apertures: Finite difference time domain (FDTD) [13–15], transmission line matrix (TLM) [9, 16], and moment of method (MoM) [17]. These numerical methods are useful for complex apertures of enclosures and also accurate, but lead to high cost, big memory on computer and high CPU time. For example, MoM technique requires thousands of seconds for running per frequency point on computers with high speed (3–4 GHz) and high capacity. So, it takes 3–4 hours to produce data containing nearly one thousand frequency points. Also different transformation codes on numerical methods take more time to get data.

We have already investigated aperture size [18] by measurement results and some parameters of magnetic shielding effectiveness (MSE) [19] by theoretical results before. In this study, computer simulating technology on electromagnetic compatibility (CST™-EMC) based on finite integration technique (FIT) in time-domain [20] is used to acquire accurate modeling results for comprehensive analysis of ESE of enclosures with apertures in 0–1 GHz in many different viewpoints. It should be noted that some studies calculate ESE of enclosure with apertures using CST microwave simulation [6, 12, 21]. Among studies in literature about SE, only a few analyze cases for some shielding parameters as aperture size, enclosure size, and enclosure depth and probe position. Unlike these studies, in this paper as the first novelty, similar shielding parameters with 18 cases are investigated and analyzed in details with cause and effect relation of electromagnetic principles to get more useful suggestions for designers. As the second novelty, the length and width of apertures, the length and width of enclosures and probe position and enclosure depth are analyzed in cross-evaluation with three-dimensional (3D) figures for selected frequencies. Therefore, many different sizes of enclosures and apertures are observed − 2209 different aperture sizes, 11521 different enclosure sizes and 3660 different enclosure depths with probe position. As a consequence, the results of cross-evaluation with 3D figures are comprehended effectively using analyzed 18 cases in detail.

Aim of this paper is first to verify CST simulation results compared with analytical formulation and measurement results and second by using this model to analyze parameters that affect ESE in details and to give suggest enclosure designers and device producers, before design process to get better performance against to EMI.

The paper is organized as follows. Section 2 gives test and measurement setup. Measurement results conducted by this setup and analytical formulation of Robinson are compared to verify CST model. Section 3 includes the analysis of simulation results of ESE versus frequency, the effects of enclosure size, aperture size, aperture shape, aperture configuration, number of apertures, probe position, 3D different aperture sizes, enclosure sizes and enclosure depth and probe distance. Section 4 contains conclusion of results investigated in Section 3 and future work.

2. TEST AND MEASUREMENT SETUP

ESE measurements were performed in the anechoic chamber at EMC Pre-Compliance Test Laboratory at Akdeniz University Industrial Based Microwave and Medical Applications Research Center (EMUMAM). This chamber is a 3m standard type having 4×4×8 m dimension. Rohde-Schwarz (SMF-100A) signal generator operating between DC and 41 GHz and Agilent (E4405B-ESA-E Series) spectrum analyzer were used as radio equipment. Pin terminals were used for 0–1 GHz as both transmitting and receiving antennas were attached above the wooden reference table and chair for avoiding any interference. Some photos of measurement process are shown in Fig. 1. A 160×160×800 mm sized enclosure was selected for ESE measurements. Details of test setup in an anechoic chamber are shown with the block diagram in Fig. 2. Measurements were carried out between 0.01 and 1 GHz with 10 MHz increments. Each measurement was repeated 20 times for each frequency, and mean values were used to reduce measurement errors.

A metallic enclosure having size of 160×160×800 mm with a single aperture size of 300×18.75 mm was preferred for all results in Fig. 3. The material of enclosure was aluminum with 2 mm thickness. The receiver probe was at the center of enclosure which was 80 mm distance to aperture. The incident angle was zero (θ = 0°) due to the normal incident plane wave, and the angle of polarization was 90° (α = 0°). As seen in Fig. 3, CST model is overlapped with others sufficiently. So, the CST results
Figure 1. Measurement setup scenes: (a) Reference measurement (Absence of enclosure); (b) Measurement with enclosure (Presence of enclosure); (c) Measurements conducted by network analyzer; (d) Enclosures having different aperture dimensions.

Figure 2. Block diagram of test set-up.

have been verified with others especially analytical model. These results allow us to continue making CST models for analyzing shielding parameters in next sections. The CST settings are used in all simulations, and the technique is FIT in time-domain. The version is CST EMC Studio-2014; the mesh shape is hexahedral; maximum mesh length is min/15 for all. The number of mesh cells and computing time are changed according to the aperture size and shape, enclosure size and shape and number of apertures. So the number of mesh cells was between 1 560 600 and 1 960 800, and the computing time took between 29–37 mins for CST-TD. It should be noted that all simulations were carried out on a personal computer using an Intel Core i7 2.60 GHz processor with 16 GB RAM and 256 GB SSD.

3. ANALYSIS OF ESE PARAMETERS

In this section, ESE is calculated for analyzing its parameters with an analogy as different 21 cases in Table 1. Each case and its parameter value used in CST simulation to calculate ESE are mentioned as: $a$ is the enclosure length, $b$ the enclosure width, $d$ the enclosure depth, $l$ the aperture length, $w$ the
aperture width and \( p \) the probe position. For all cases, the frequency range is 0–1 GHz. The thickness of metallic enclosure is 2 mm; the incident angle is zero (\( \theta = 0^\circ \)) due to the normal incident plane wave; the angle of polarization is 90\(^\circ\) (\( \alpha = 0^\circ \)). The effect of enclosure size, aperture size, probe location, aperture shape, multiple apertures and aperture configuration are investigated as indicated in Figs. 4–14. Generally, for 0–1 GHz interval, ESE decreases with increased frequency until resonant frequencies. Onwards resonant frequencies, ESE increases with increased frequency. This result can be explained as that wave length is inversely correlated with frequency. If the wave length is low (with increased frequency), higher amplitude of electrical field get in to aperture of enclosure. At resonance frequency, ESE is negative, which means that there are such sources which lead to the rise of noise and interference. That is the unwanted case for shielding and why we have high ESE at low frequencies in CST model.

3.1. Effect of Enclosure Size

In Fig. 4 for cases 1, 2 and 3, ESE is 43.63, 41.46 and 38.65 dB at 200 MHz (below resonant frequency) and 28.09, 11.16 and -16.12 dB, respectively at 880 MHz (above resonant frequency). So, when the enclosure size is increased from 700 \( \times \) 120 \( \times \) 160 mm to 800 \( \times \) 200 \( \times \) 240 mm, ESE is 4.98 dB higher at 200 MHz and 44.2 dB higher at 880 MHz. At same frequencies, ESE gets higher with increased enclosure size. These results can be explained with Eqs. (2a), (2b), (2c) and (2d) as given below [22]. In these equations for TE (Transverse Electric) modes, the amplitude of electric field \( E_x \) and \( E_y \) which gets into aperture of enclosure is decreased with increased enclosure size (\( a, b \) and \( d \)). So it is possible to increase
Table 1. The cases and its parameter values used in CST simulation to calculate ESE.

<table>
<thead>
<tr>
<th>Case Number</th>
<th>Analysis Description</th>
<th>$a$ (mm)</th>
<th>$b$ (mm)</th>
<th>$d$ (mm)</th>
<th>$p$ (mm)</th>
<th>Probe (Center or not)</th>
<th>$l$ (mm)</th>
<th>$w$ (mm)</th>
<th>Number of apertures</th>
<th>The total open area of apertures (mm$^2$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Case 1</td>
<td>Effect of enclosure size</td>
<td>700</td>
<td>120</td>
<td>160</td>
<td>80</td>
<td>✓</td>
<td>150</td>
<td>37.5</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 2</td>
<td>Effect of aperture size</td>
<td>750</td>
<td>160</td>
<td>200</td>
<td>100</td>
<td>✓</td>
<td>150</td>
<td>37.5</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 3</td>
<td></td>
<td>800</td>
<td>200</td>
<td>240</td>
<td>120</td>
<td>✓</td>
<td>150</td>
<td>37.5</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 4</td>
<td>Effect of aperture size</td>
<td>800</td>
<td>160</td>
<td>160</td>
<td>100</td>
<td>✓</td>
<td>55</td>
<td>55</td>
<td>1</td>
<td>3025</td>
</tr>
<tr>
<td>Case 5</td>
<td></td>
<td>800</td>
<td>160</td>
<td>160</td>
<td>100</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 6</td>
<td></td>
<td>800</td>
<td>160</td>
<td>160</td>
<td>100</td>
<td>✓</td>
<td>95</td>
<td>95</td>
<td>1</td>
<td>9025</td>
</tr>
<tr>
<td>Case 7</td>
<td>Effect of aperture shape</td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>100</td>
<td>4</td>
<td>1</td>
<td>100</td>
</tr>
<tr>
<td>Case 8</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>4</td>
<td>25</td>
<td>1</td>
<td>100</td>
</tr>
<tr>
<td>Case 9</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>25</td>
<td>4</td>
<td>1</td>
<td>100</td>
</tr>
<tr>
<td>Case 10</td>
<td>Effect of aperture configuration</td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>10</td>
<td>5</td>
<td>8</td>
<td>400</td>
</tr>
<tr>
<td>Case 11</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>25</td>
<td>4</td>
<td>3</td>
<td>300</td>
</tr>
<tr>
<td>Case 12</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>25</td>
<td>4</td>
<td>5</td>
<td>500</td>
</tr>
<tr>
<td>Case 13</td>
<td>Effect of aperture size</td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 14</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 15</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 16</td>
<td>Effect of aperture size</td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 17</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 18</td>
<td></td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 19</td>
<td>Effect of aperture size</td>
<td>160</td>
<td>160</td>
<td>800</td>
<td>80</td>
<td>✓</td>
<td>3 mm</td>
<td>3 mm</td>
<td>1</td>
<td>400–24964</td>
</tr>
<tr>
<td>Case 20</td>
<td>Effect of enclosure size</td>
<td>100–200</td>
<td>2.5 mm</td>
<td>2.5 mm</td>
<td>800</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
<tr>
<td>Case 21</td>
<td>Effect of probe position</td>
<td>160</td>
<td>160</td>
<td>3 mm</td>
<td>3 mm</td>
<td>✓</td>
<td>75</td>
<td>75</td>
<td>1</td>
<td>5625</td>
</tr>
</tbody>
</table>

ESE in CST model via increasing enclosure size.

\[ E_x = \frac{\beta_x}{\varepsilon} A_{mnp} \cos (\beta_x x) \sin (\beta_y y) \sin (\beta_z z) \text{ (V/m)} \]  \hspace{1cm} (2a)

\[ E_y = -\frac{\beta_x}{\varepsilon} A_{mnp} \sin (\beta_x x) \sin (\beta_y y) \sin (\beta_z z) \text{ (V/m)} \]  \hspace{1cm} (2b)

\[ E_z = 0 \text{ (V/m)} \]  \hspace{1cm} (2c)

\[ \beta_x = \frac{m\pi}{a}, \quad \beta_y = \frac{n\pi}{b}, \quad \beta_z = \frac{p\pi}{d} \text{ (rad/m)} \]  \hspace{1cm} (2d)
Here $\beta_x$, $\beta_y$, and $\beta_z$ are the components of phase constants of TE mode plane EM wave; $A_{mnp}$ is the amplitude of the electric field; $\varepsilon$ is the dielectric constant of the medium where $m, n, p = 0, 1, 2, 3, \ldots$, except $m = n \neq 0$.

As seen in Fig. 4, for cases 1, 2 and 3, resonance frequency is 640, 750 and 880 MHz, respectively, which means that resonance frequency decreases with increased enclosure size. This result can be explained with Eq. (3) [22], and resonance frequency decreases with increased enclosure size values ($a$, $b$ and $d$). That is why in case 3, lower resonance frequency is 640 MHz. The resonance frequency of TE mode is given by

$$ (f_{\text{resonance}})_{mnp}^{TE} = \frac{1}{2\pi \sqrt{\mu \varepsilon}} \sqrt{\left(\frac{m\pi}{a}\right)^2 + \left(\frac{n\pi}{b}\right)^2 + \left(\frac{p\pi}{d}\right)^2} \text{ (Hz)} $$

where $m, n, p = 0, 1, 2, 3, \ldots$, except that $m = n \neq 0$ and that $\mu$ and $\varepsilon$ are the permeability and dielectric constant of the enclosure material, respectively.

### 3.2. Effect of Aperture Size

For cases 4, 5 and 6, ESE is 45.23, 39.49 and 34.84 dB, respectively at 200 MHz, which means that ESE gets 10.78 dB higher when the aperture size is decreased from $95 \times 95$ mm to $55 \times 55$ mm. At the same frequencies, ESE has increased with decreased aperture size. This situation can be explained with Eq. (4) [22] as:

$$ P_e = \frac{1}{2} \int_S \text{Re} \left\{ \vec{E} \times \vec{H}^* \right\} \cdot d\vec{S} \text{ (W)} $$

$P_e$ is the existing total power of surface $S$. Increased aperture size means that area of aperture increases by differential surface elements $d\vec{S}$ as seen in Eq. (4). So, ESE gets higher with increased aperture size. As seen in Fig. 5, for cases 4, 5 and 6, ESE has the same resonance frequency 940 MHz in these cases due to the same enclosure size as discussed before with Eq. (3).

![Figure 5. Simulation results of ESE versus frequency for case 4, 5 and 6 on Table 1.](image)

### 3.3. Effect of Aperture Shape

For cases 7, 8 and 9, the total open area of apertures is fixed as 100 mm$^2$. Resonance frequency has no change as 955 MHz, as explained with Eq. (3). ESE changes with the ratio of aperture length/width. For cases 7, 8 and 9, the ratios of aperture length/width are 1, 0.16 and 6.25 as seen in Fig. 6. When the aperture has long length with short width, ESE gets higher. At the same frequency sample point at 200 MHz, ESE is 86.13, 71.98 and 99.86, respectively. When the aperture size is modified from $4 \times 25$ mm to $25 \times 4$ mm, ESE gets 27.88 dB higher. This result can be explained with Fig. 7. Perpendicular polarization of the electric field is vertical to travelling plane of the wave. So the direction of electric
field and the location of aperture width have the same direction, which means that when the aperture width is higher, high amplitude of electric field gets into aperture of enclosure. Then, from Eqs. (2a) and (2b), ESE becomes worse with increased amplitude $A_{nmp}$ of electric field. Finally, ESE is decreased with increased aperture width. It can be remembered that cases 7, 8 and 9’s aperture widths are 10, 25 and 4 mm, respectively. ESE has the best value 99.86 dB when aperture width is at the lowest value of 4 mm @ 500 MHz. As a result, ESE changes with polarization of plane wave and the direction of electric field according to the aperture shape (in this situation, it is aperture width).

![Figure 6](image)

**Figure 6.** Simulation results of ESE versus frequency for case 7, 8 and 9 on Table 1.

![Figure 7](image)

**Figure 7.** The location of plane wave and its parameters: Perpendicular polarization of TE mode means the angle of polarization ($\alpha = 90^\circ$) (the angle between electric field and travelling wave direction z-axis), the incident angle $\theta = 0^\circ$ (the angle between traveling wave $\hat{k}$ and z-axis) and other incident angle ($\Phi = 90^\circ$) (the angle from positive x-axis on x-y plane up to 360$^\circ$).

### 3.4. Effect of Aperture Configuration

For cases 10, 11 and 12, resonance frequency does not change at 935 MHz as indicated from Eq. (3) and as seen in Fig. 8. As discussed before for perpendicular polarization, aperture width of enclosure and total open area of aperture of enclosure affect ESE. For cases 10, 11 and 12, aperture width is nearly the same as 4 and 5 mm. The total open area of aperture(s) is fixed as 400 mm². In this situation, effect of the number of apertures is analyzed. For cases 10, 11 and 12, ESE is 90.42, 81.85 and 64.12 dB, respectively. At the same frequency, ESE gets rising with decreased number of apertures when total open area of aperture(s) is fixed. While the number of apertures decreases from 8 to 1, ESE gets 26.3 dB higher.
3.5. Effect of Number of Apertures

For cases 13, 14 and 15, resonance frequency has no change as 950 MHz, as discussed in Section 3.4. It is better to minimize number of apertures on enclosure when the total open area of aperture(s) is fixed. While the total open area aperture(s) is increased for cases 13, 14 and 15, number of aperture(s) is analyzed here. At the same frequency, ESE gets higher with decreased number of apertures. In Fig. 9 for cases 13, 14 and 15, ESE is 71.98, 62.54 and 71.98 dB, respectively, at 200 MHz. When the number of apertures is increased from 1 to 5, ESE gets 13.78 dB higher. The reason of this improvement (total open area of aperture) is explained in Section 3.2 that ESE gets higher with increased aperture size. While the number of apertures decreases from 8 to 1, as noted before in Section 3.4, ESE gets 26.3 dB higher. So, simulations tell us that the effect of aperture number is more effective than total area of apertures on electric shielding.

3.6. Effect of Probe Position

For cases 16, 17 and 18, resonance frequency has no change as 935 MHz. At the same frequency, when the distance between probe location and aperture is far, ESE gets better. In Fig. 10, for cases 16, 17 and 18, ESE is 32.76, 39.42 and 46.09 dB, respectively at 200 MHz. When the probe position $p$ of enclosure (the distance between enclosure front surface and probe location) is moved from 40 mm to 120 mm, ESE gets 13.33 dB higher. This improvement (probe is far away from aperture) can be explained by Eq. (5) as known Friis transmission equation, and it relates the power $P_r$ (delivered to the receiver load) to the
input power of the transmitting antenna $P_t$. The term $(\lambda/4\pi R)^2$ is called free-space loss factor, and it takes into account the losses due to the spherical spreading of the energy by the antenna. $G_{0t}$ and $G_{0r}$ are the gains of transmitting and receiving antennas in the directions $0t$ and $0r$, respectively [23]. In simulations, plane wave is out of enclosure (Transmitter propagates plane wave), and receiver probe is in the enclosure. Eq. (5) tells us that receiver power is inversely proportional to squared distance. While the transmitter wave is travelling, in simulation model, on $z$-axis as seen in Fig. 7, power of wave decreases. When the probe distance is increased, power of wave decreases. Friis transmission equation is given as:

$$\frac{P_r}{P_t} = \left(\frac{\lambda}{4\pi R}\right)^2 G_{0t} G_{0r}$$

(5)

### 3.7. Effect of Aperture Sizes by 3D Investigation

For cases 4, 5 and 6, three apertures which have different sizes are investigated as discussed before in Fig. 5. For case 19 in Fig. 11, aperture width and length are changed linearly from 20 to 158 mm with 3 mm increment. 47 apertures having different lengths, 47 apertures having different widths, totally 2209 (47 $\times$ 47) different aperture sizes are used. So, all possible square and rectangular sizes are computed for ESE. From the top to bottom, the selected frequencies are 50, 500 and 950 MHz, respectively. ESE gets better with decreased frequency as discussed before. Since 950 MHz is resonance frequency or too close to resonance frequency, there is a valley at this frequency.

At 50 MHz, when the aperture length is fixed as 20 $\sim$ 23 mm and the aperture width increased from 20 to 158 mm, ESE gets 36.08 dB lower as seen in Fig. 11. This decrease is due to increased total open area of apertures on enclosure as discussed before in Section 3.2. When the aperture length is fixed and the width increased at the same time, the total open area of aperture is increased, so the influence of power keeps ESE lower. At 50 MHz, when the aperture width is fixed as 158 mm and the aperture length increased from 23 to 158 mm, ESE gets 12.01 dB lower. This decrease can also be explained in Section 3.2.

As discussed above, when the aperture length is decreased nearly 6 times (from 23 to 158 mm), ESE gets 12.01 dB better. But when the aperture width is decreased nearly 6 times (from 20 to 158 mm), ESE gets 36.08 dB better. It means that aperture width is more effective on ESE than aperture length. This result can also be seen in Table 2. While the aperture length is decreased from 160 to 20 mm, ESE averagely gets only 1.42 dB better. However, when the aperture width is decreased from 160 to 20 mm, ESE averagely gets 5.14 dB better. The more effect is due to the perpendicular polarization as discussed in Section 3.3. The direction of incident electric field is corresponding to aperture width. To verify the conclusion of these results, ESE has also been computed with parallel polarization as seen in Fig. 12. In this situation, aperture length is more effective on ESE than aperture width this time. So, the conclusion of these results as discussed above has been verified.
Figure 11. Simulation results of ESE versus aperture width and length for case 19 (Perpendicular Polarization).

Table 2. ESE values versus aperture width and length (Aperture width and length size modified 20 mm each).

<table>
<thead>
<tr>
<th>(w, l) [mm]</th>
<th>(20, 20)</th>
<th>(20, 40)</th>
<th>(20, 60)</th>
<th>(20, 80)</th>
<th>(20, 100)</th>
<th>(20, 120)</th>
<th>(20, 140)</th>
<th>(20, 160)</th>
</tr>
</thead>
<tbody>
<tr>
<td>ESE [dB]</td>
<td>85</td>
<td>83</td>
<td>81</td>
<td>80</td>
<td>78</td>
<td>76</td>
<td>75</td>
<td>74</td>
</tr>
<tr>
<td>(w, l) [mm]</td>
<td>(20, 20)</td>
<td>(40, 20)</td>
<td>(60, 20)</td>
<td>(80, 20)</td>
<td>(100, 20)</td>
<td>(120, 20)</td>
<td>(140, 20)</td>
<td>(160, 20)</td>
</tr>
<tr>
<td>ESE [dB]</td>
<td>85</td>
<td>72.5</td>
<td>66</td>
<td>61</td>
<td>57</td>
<td>54</td>
<td>51</td>
<td>49</td>
</tr>
</tbody>
</table>

Figure 12. Simulation results of ESE versus aperture width and length for case 19 (Parallel Polarization).

3.8. Effect of Enclosure Size by 3D Investigation

As discussed before in Fig. 4, for cases 1, 2 and 3, three enclosures which have different sizes are designed. In Fig. 13 for case 20, enclosure depth is fixed as 160 mm for all situations. Enclosure length (a) is varied linearly from 100 to 800 mm with 18 mm increment. Enclosure width (b) is varied linearly from 100 to 200 mm with 2.55 mm increment. 41 enclosures having different lengths, 280 enclosures having different widths, totally 11521 (41 × 281) different enclosure sizes have been used. So, all possible enclosure lengths and widths have been analyzed for ESE. In Fig. 13, from top to bottom, selected frequencies are 50, 500 and 950 MHz, respectively. As seen, ESE gets better with decreased frequency as discussed...
Figure 13. Simulation results of ESE versus enclosure width and length for case 20 on Table 1.

before. Since 950 MHz is resonance frequency or too close to resonance frequency, there is a valley at 950 MHz.

At 50 MHz, when the enclosure length \(a\) is fixed as 800 mm and the enclosure width \(b\) varied from 100 to 200 mm, ESE gets just 0.41 dB better. However, when the enclosure width \(b\) is fixed as 200 mm and enclosure length \(a\) modified from 100 to 800 mm, ESE gets just 3.88 dB better. The effect of modified values of sizes (100 mm for enclosure width and 700 mm for enclosure length) on ESE is only 0.41 dB and 3.88 dB, so these results can be ignored. The same conclusions can be seen also at 500 MHz. But similar conclusion is not seen at resonance frequency or the frequency close to resonance frequency. For example, at 950 MHz when enclosure width is decreased from 200 to 100 mm, ESE is significantly increased from \(-17\) to \(26\) dB. It means that there is a 43 dB improvement on ESE. At 950 MHz when enclosure length is decreased from 800 to 100 mm, ESE is increased from \(-16\) to \(-11\) dB. It means that there is only 5 dB improvement on ESE in this situation. At 50 and 500 MHz, there is no significant effect. At 950 MHz, the effect of enclosure width (43 dB) is more important than the effect of enclosure width (5 dB) due to the direction of incidence electric field as discussed before. That is why in resonance region, designers need optimization to rescue devices from negative shielding.

3.9. Effect of Probe Position and Enclosure Depth by 3D Investigation

As discussed before in Fig. 10, effect of three different probe positions on ESE is investigated. In Fig. 14 for case 21, the probe position \(p\) and enclosure depth \(d\) are varied from 20 to 200 mm with 2.3 mm increment. 61 enclosures having different depths, 60 enclosures having different probe positions, totally 3660 \((61 \times 60)\) different enclosure cases have been used. All situations in which enclosure depth \(d\) is bigger than the probe position \(p\) have been analyzed.

At 50 MHz, while the enclosure depth \(d\) is fixed as 200 mm and the probe position \(p\) moved away from 20 to 197 mm, ESE gets 58.7 dB better. The reason for these results is the same as that in Section 3.6. At 500 MHz, when the probe position \(p\) is fixed as 60 mm and the enclosure depth \(d\) moved away from 63.29 to 200 mm, ESE gets 36 dB better (from 43.85 to nearly 80 dB).

Except resonance frequencies (at 50 and 500 MHz), we recommend that it is better to increase enclosure depth \(d\) and probe position \(p\). But at resonance frequencies (at 950 MHz here), when the enclosure depth is high and probe position low, there is a different and important region as seen in the left of Fig. 14. There is an improvement on ESE in this special region as also seen in Table 3. The highest ESE values at 950 MHz are seen in Table 3 for different 7 points where the ratio of \(d/p\) is increased from 5.2 to 7 and then fixed as 7. In this special region, maximum ESE value is 57.85 dB, when enclosure depth is 200 mm and probe position 38 mm. At 50 MHz when the enclosure depth and probe position are 50.76 mm and 79.24 mm, respectively, ESE is the highest with 50.84 dB. But at 950 MHz in the special region, ESE is the highest with 57.85 dB. So, it is 6.01 dB higher than the peak value at 50 MHz. This conclusion tells us that special regions are important for resonance frequencies.
Figure 14. Simulation results of ESE versus probe position and enclosure depth for case 21 on Table 1.

Table 3. Investigation of enclosure depth (d), probe position (p) and the ratio of d/p at 950 MHz on Figure 14.

<table>
<thead>
<tr>
<th>ESE (dB)</th>
<th>57.85</th>
<th>57.4</th>
<th>56.95</th>
<th>56.46</th>
<th>55.92</th>
<th>55.33</th>
<th>54.68</th>
</tr>
</thead>
<tbody>
<tr>
<td>Enclosure depth d [mm]</td>
<td>200</td>
<td>197.7</td>
<td>195.4</td>
<td>193.2</td>
<td>190.9</td>
<td>188.6</td>
<td>186.3</td>
</tr>
<tr>
<td>Probe position p [mm]</td>
<td>38</td>
<td>35.95</td>
<td>33.67</td>
<td>31.39</td>
<td>29.11</td>
<td>26.84</td>
<td>26.54</td>
</tr>
<tr>
<td>d/p ratio</td>
<td>5.20</td>
<td>5.50</td>
<td>5.80</td>
<td>6.15</td>
<td>6.55</td>
<td>7.00</td>
<td>7.00</td>
</tr>
</tbody>
</table>

4. CONCLUSION AND FUTURE WORK

Metallic shielding enclosures are used to reduce radiation from external electromagnetic fields and exudation effects from interior devices as examples which are mainboard circuits, Wi-Fi transceivers, RAMs, sub-boards, solid-state drives (SSD), etc. in a computer case, laptop or TV. As a fact, the required slots and apertures on enclosures for heat allocation, ventilation, I/O cable, etc. induce the coupling route of EMI from the inside to outside. So, the investigation of SE becomes important for designing metallic enclosures of EMI sensitive devices in manufacturing process. When ESE is negative, it is a harmful situation for devices as known. Thus, the device producers need to calculate resonance frequency of enclosure at first against electric interference before the design of device enclosure. ESE is always higher in lower frequencies, so devices should be operated in small frequency whenever possible to get higher performance and quality. We give detailed comments depending on simulated results of ESE parameters noted in Section 3 as the following:

√ First, increasing the enclosure size makes ESE higher, and that is why designers should prefer larger size of enclosure. Second, since the operating frequency of device and the resonance frequency of enclosure are the same or close to each other, a) producers need to adjust device parameters to change operating frequency, and b) they need to modify enclosure size (prefer increasing as discussed above) to change resonance frequency.

√ When aperture shape is square, using small aperture size on enclosures makes ESE better. In this situation, designers are required to identify the polarization of incident electric field. For parallel polarization decreasing aperture length and for perpendicular polarization decreasing aperture width are more effective on ESE. First, designers should decrease aperture width for perpendicular polarization. Second, if the polarization is fixed, they need locate the aperture on enclosure according to the direction of incident angle. Third, producers need locate devices into enclosure according to the aperture width/length ratio. It is important to note that aperture area has no change in these modifications.
Minimizing number of apertures makes ESE better while total open area of aperture(s) is fixed. So, device producers should use fewer apertures. But when the total area of aperture(s) is not fixed, increasing number of used apertures makes ESE higher, so designers should use more apertures in this manner.

Increasing probe distance gets ESE higher. So, it is better for designers to locate device/circuit as far away from aperture(s) of enclosure as possible and to find the best direction of device according to the aperture size and polarization to improve quality. But at resonance frequencies, there is a special region where \( d/p \) ratio is 5.2–7 and ESE the highest, and optimization engineers should not ignore this effective region for resonance frequencies.

In computer enclosures there are many apertures with different geometrical shapes for airing, I/O connections and other purposes. This paper provides that insight about effect of rectangular aperture number, configuration, etc. on ESE. In our future work, for a sample computer box, the effect of round, hexagonal and triangle apertures on ESE will be investigated. Then, according to these effects, location and polarization of mainboard, hard disc, airing fan, etc. will be tried to determine.

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